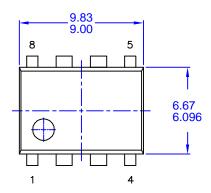
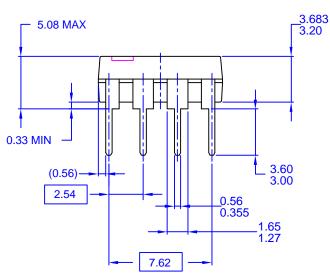
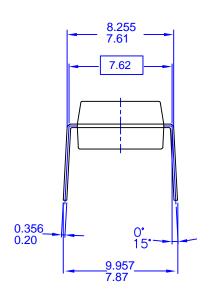
THIS DRAWING IS THE PROPERTY OF FAIRCHILD SEMICONDUCTOR CORPORATION, NO USE THEREOF SHALL BE AMDE OTHER THAN AS A REFERENCE FOR PROPOSALS AS SUBMITTED TO FAIRCHILD SEMICONDUCTOR CORPORATION FOR JOBS TO BE EXECUTED IN CONFORMITY WITH SUCH PROPOSALS UNLESS THE CONSENT OF SAID FAIRCHLE SEMICONDUCTOR OF PORATION HAS PREVIOUSLY BEEN OBTAINED, NO PART OF THIS DRAWING SHALL BE COPIED OR DUFFLACED OR TIS CONTENTS DISCLOSED. THE INFORMATION CONTAINED

REVISIONS									
LTR	DESCRIPTION	E.D.C.N.	DATE	BY/APP'D					
Α	RELEASE TO DOCUMENT CONTROL		05 <b>APR2004</b>	OS.JEON					
2	Dimension Composition	ECN-MKT-N08FR2	<b>2</b> AUG 2007	H.ALLEN					







NOTES: UNLESS OTHERWISE SPECIFIED

- A) THIS PACKAGE CONFORMS TO JEDEC MS-001 VARIATION BA
- B) ALL DIMENSIONS ARE IN MILLIMETERS.
- C) DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.
- D) DIMENSIONS AND TOLERANCES PER ASME Y14.5M-1994
- E) DRAWING FILENAME AND REVSION: MKT-N08FREV2.

APPROVALS	DATE						
J. H MOON	22MAY2007	FAII	RC	HILC			
CHECKED: J. H MOON 22MAY20		SEMICONDUCTOR+					
APPROVED: T. S KIM 22MAY2007		8LD, MDIP, JEDEC MS-001					
		.300" WIDE					
PROJECTION		3CALE 1:1	SIZE NA	DRAWING NUMBER	MKT-N08F		
INCH EMMI	FORMERLY:	N/A		SHEET : 1 (	OF 1		